# **BLF8G22LS-270V**; Power LDMOS transistor Rev. 3 — 1 September 2015

**AMPLEON** 

Product data sheet

### **Product profile**

### 1.1 General description

270 W LDMOS power transistor with improved video bandwidth for base station applications at frequencies from 2110 MHz to 2170 MHz.

#### Table 1. Typical performance

Typical RF performance at T<sub>case</sub> = 25 °C in a common source class-AB production test circuit, tested on straight lead device.

| Test signal      | f            | I <sub>Dq</sub> | V <sub>DS</sub> | $P_{L(AV)}$ | Gp   | $\eta_{D}$ | ACPR <sub>5M</sub> |
|------------------|--------------|-----------------|-----------------|-------------|------|------------|--------------------|
|                  | (MHz)        | (mA)            | (V)             | (W)         | (dB) | (%)        | (dBc)              |
| 2-carrier W-CDMA | 2110 to 2170 | 2400            | 28              | 80          | 17.3 | 29         | -29 <u>[1]</u>     |

<sup>[1] 3</sup>GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF; 5 MHz carrier spacing.

### 1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R<sub>th</sub> providing excellent thermal stability
- Designed for broadband operation
- Decoupling leads to enable improved video bandwidth (80 MHz typical)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 2110 MHz to 2170 MHz frequency range

# 2. Pinning information

Table 2. Pinning

| Pin     | Description         | Simplified outline            | Graphic symbol  |
|---------|---------------------|-------------------------------|-----------------|
|         | 2LS-270V (SOT1244B) | Spiined oddine                | C. apino Symbol |
|         |                     |                               |                 |
| 1       | drain               | 4 1 5                         | 1               |
| 2       | gate                |                               | 6,7 →   4,5     |
| 3       | source              |                               | 2               |
| 4       | video lead          |                               | 3               |
| 5       | video lead          |                               | aaa-003619      |
| 6       | n.c.                |                               |                 |
| 7       | n.c.                | $\frac{1}{6}$ 2 $\frac{7}{7}$ |                 |
| BLF8G22 | LS-270GV (SOT1244C) |                               |                 |
| 1       | drain               | 4 4 5                         | 4               |
| 2       | gate                | 4 1 5                         | 6,7 →   1 4,5   |
| 3       | source              | [1]                           | 2               |
| 4       | video lead          |                               | 2               |
| 5       | video lead          | 6 2 7                         | aaa-003619      |
| 6       | n.c.                | 6 2 17                        |                 |
| 7       | n.c.                |                               |                 |

<sup>[1]</sup> Connected to flange.

# 3. Ordering information

Table 3. Ordering information

| Type number     | Packag | Package                                  |          |  |  |
|-----------------|--------|--|----------|--|--|
|                 | Name   | Description                              | Version  |  |  |
| BLF8G22LS-270V  | -      | earless flanged ceramic package; 6 leads | SOT1244B |  |  |
| BLF8G22LS-270GV | -      | earless flanged ceramic package; 6 leads | SOT1244C |  |  |

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Parameter            | Conditions   | Min  | Max   | Unit  |
|----------------------|--|--|---|---|
| drain-source voltage |  | -  | 65  | V   |
| gate-source voltage  |  | -0.5   | +13   | V   |
| storage temperature  |  | -65  | +150  | °C  |
| junction temperature |  | -  | 225   | °C  |
|                      | drain-source voltage<br>gate-source voltage<br>storage temperature | drain-source voltage gate-source voltage storage temperature | drain-source voltage - gate-source voltage -0.5 storage temperature -65 | drain-source voltage - 65 gate-source voltage -0.5 +13 storage temperature -65 +150 |

### 5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol               | Parameter                                | Conditions                       | Тур  | Unit |
|----------------------|--|----------------------------------|------|------|
| R <sub>th(j-c)</sub> | thermal resistance from junction to case | $T_{case}$ = 80 °C; $P_L$ = 50 W | 0.26 | K/W  |

### 6. Characteristics

### Table 6. DC characteristics

 $T_i = 25$  °C; per section unless otherwise specified.

| Symbol              | Parameter                        | Conditions   | Min | Тур  | Max | Unit |
|---------------------|----------------------------------|--|-----|------|-----|------|
| $V_{(BR)DSS}$       | drain-source breakdown voltage   | $V_{GS} = 0 \text{ V}; I_D = 4.5 \text{ mA}$                       | 65  | -    | -   | V    |
| $V_{GS(th)}$        | gate-source threshold voltage    | $V_{DS}$ = 10 V; $I_{D}$ = 450 mA                                  | 1.5 | 1.8  | 2.3 | V    |
| I <sub>DSS</sub>    | drain leakage current            | $V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$                      | -   | -    | 4.2 | μΑ   |
| I <sub>DSX</sub>    | drain cut-off current            | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$<br>$V_{DS} = 10 \text{ V}$ | -   | 80   | -   | Α    |
| I <sub>GSS</sub>    | gate leakage current             | $V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$                      | -   | -    | 420 | nΑ   |
| g <sub>fs</sub>     | forward transconductance         | $V_{DS}$ = 10 V; $I_{D}$ = 450 mA                                  | -   | 3.8  | -   | S    |
| R <sub>DS(on)</sub> | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$<br>$I_D = 15.75 \text{ A}$ | -   | 0.04 | -   | Ω    |

### Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; PAR = 8.4 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1-64 DPCH;  $f_1$  = 2112.5 MHz;  $f_2$  = 2117.5 MHz;  $f_3$  = 2162.5 MHz;  $f_4$  = 2167.5 MHz; RF performance at  $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA;  $T_{case}$  = 25 °C; unless otherwise specified; in a class-AB production test circuit, tested on straight lead device.

| Symbol             | Parameter                            | Conditions                 | Min  | Тур  | Max   | Unit |
|--------------------|--------------------------------------|----------------------------|------|------|-------|------|
| Gp                 | power gain                           | $P_{L(AV)} = 80 \text{ W}$ | 16.3 | 17.3 | -     | dB   |
| RLin               | input return loss                    | $P_{L(AV)} = 80 \text{ W}$ | -    | -17  | -7    | dB   |
| $\eta_{D}$         | drain efficiency                     | $P_{L(AV)} = 80 \text{ W}$ | 26   | 29   | -     | %    |
| ACPR <sub>5M</sub> | adjacent channel power ratio (5 MHz) | $P_{L(AV)} = 80 \text{ W}$ | -    | -29  | -26.5 | dBc  |

### 7. Test information

### 7.1 Ruggedness in class-AB operation

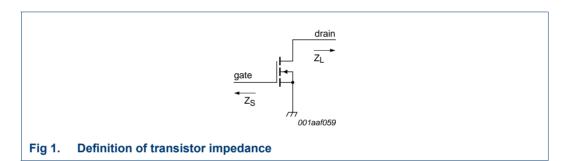
The BLF8G22LS-270V and BLF8G22LS-270GV are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA;  $P_L$  = 270 W (CW); f = 2110 MHz.

### 7.2 Impedance information

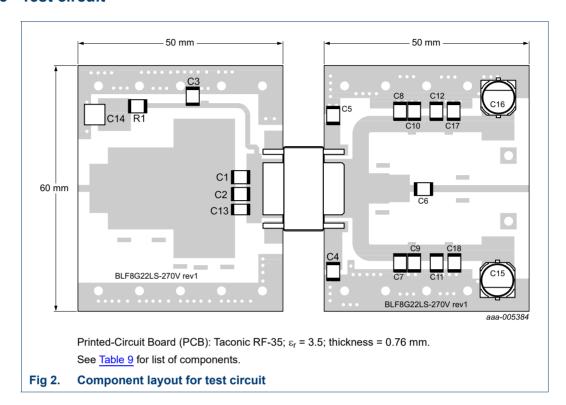
Table 8. Typical impedance information

 $I_{Dq}$  = 2400 mÅ; main transistor  $V_{DS}$  = 28 V.  $Z_S$  and  $Z_L$  defined in Figure 1.

| f               | Z <sub>S</sub> | Z <sub>L</sub> |
|-----------------|----------------|----------------|
| (MHz)           | (Ω)            | $(\Omega)$     |
| BLF8G22LS-270V  |                |                |
| 2110            | 0.68 – j4.73   | 2.42 – j2.08   |
| 2140            | 0.80 - j4.94   | 2.67 – j2.24   |
| 2170            | 0.96 – j5.37   | 2.68 – j2.24   |
| BLF8G22LS-270GV |                |                |
| 2110            | 1.23 – j6.94   | 2.39 – j4.22   |
| 2140            | 1.43 – j7.42   | 2.68 – j4.22   |
| 2170            | 1.44 – j7.50   | 2.90 – j4.30   |



### 7.3 Test circuit

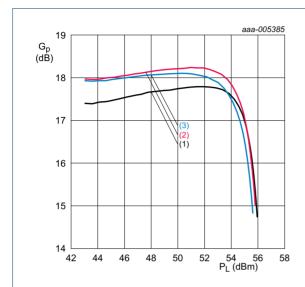


**Table 9.** List of components For test circuit, see Figure 2.

| Component         | Description                       | Value                         | Remarks                      |
|-------------------|-----------------------------------|-------------------------------|------------------------------|
| C1, C2            | multilayer ceramic chip capacitor | 0.7 pF                        | ATC100B                      |
| C3                | multilayer ceramic chip capacitor | 47 pF                         | ATC100B                      |
| C4, C5, C17, C18  | multilayer ceramic chip capacitor | $4.7~\mu\text{F},50~\text{V}$ | Murata                       |
| C6                | multilayer ceramic chip capacitor | 33 pF                         | ATC100B                      |
| C7, C8            | multilayer ceramic chip capacitor | 12 pF                         | ATC100B                      |
| C9, C10, C11, C12 | multilayer ceramic chip capacitor | 100 pF                        | ATC100B                      |
| C13               | multilayer ceramic chip capacitor | 0.2 pF                        | ATC100B                      |
| C14               | multilayer ceramic chip capacitor | 10 $\mu$ F, 50 V              | Murata; SMD 2220             |
| C15, C16          | electrolytic capacitor            | 470 $\mu$ F, 63 V             |                              |
| R1                | resistor                          | 5.1 Ω                         | SMD 1206;<br>tolerance = 1 % |

### 7.4 Graphs

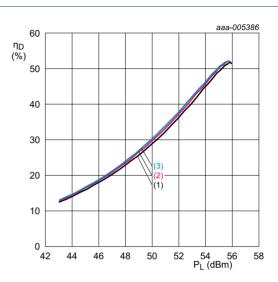
### 7.4.1 Pulsed CW



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA;  $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %.

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

Fig 3. Power gain as a function of output power; typical values

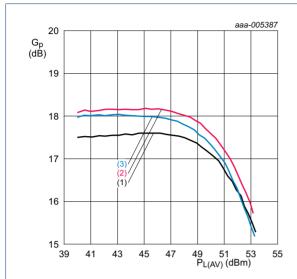


 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA;  $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %.

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

Fig 4. Drain efficiency as a function of output power; typical values

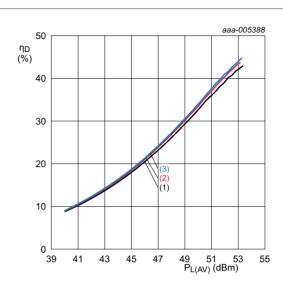
### 7.4.2 IS-95



 $V_{DS} = 28 \text{ V}; I_{Dq} = 2400 \text{ mA}.$ 

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

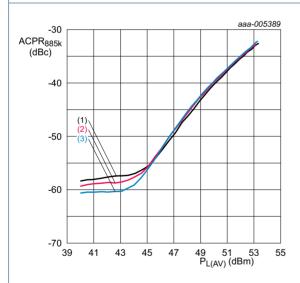
Fig 5. Power gain as a function of average output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA.

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

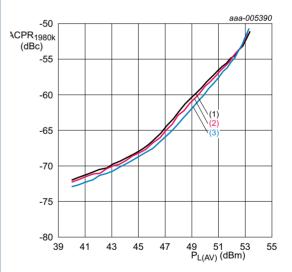
Fig 6. Drain efficiency as a function of average output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA.

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

Fig 7. Adjacent channel power ratio (885 kHz) as a function of average output power; typical values

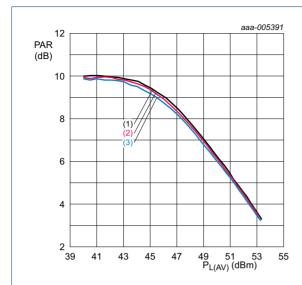


 $V_{DS} = 28 \text{ V}; I_{Dq} = 2400 \text{ mA}.$ 

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

Fig 8. Adjacent channel power ratio (1980 kHz) as a function of average output power; typical values

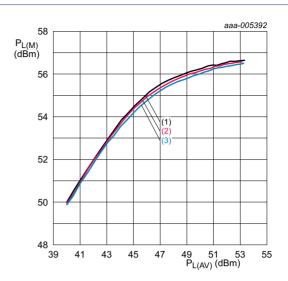
**Power LDMOS transistor** 



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA.

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

Fig 9. Peak-to-average power ratio as a function of average output power; typical values

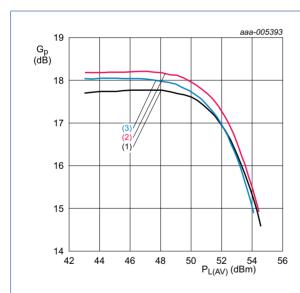


 $V_{DS} = 28 \text{ V}; I_{Dq} = 2400 \text{ mA}.$ 

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

Fig 10. Peak output power ratio as a function of average output power; typical values

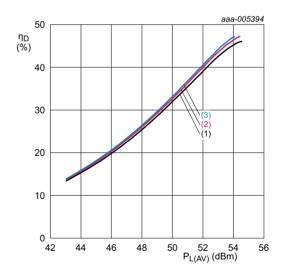
### 7.4.3 1-carrier W-CDMA



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA.

- (1) f = 2112.5 MHz
- (2) f = 2140 MHz
- (3) f = 2167.5 MHz

Fig 11. Power gain as a function of average output power; typical values

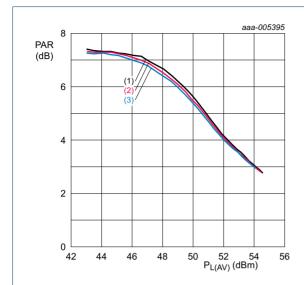


 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA.

- (1) f = 2112.5 MHz
- (2) f = 2140 MHz
- (3) f = 2167.5 MHz

Fig 12. Drain efficiency as a function of average output power; typical values

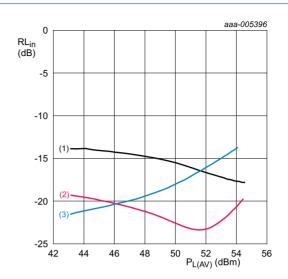
**Power LDMOS transistor** 



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA.

- (1) f = 2112.5 MHz
- (2) f = 2140 MHz
- (3) f = 2167.5 MHz

Fig 13. Peak-to-average power ratio as a function of average output power; typical values

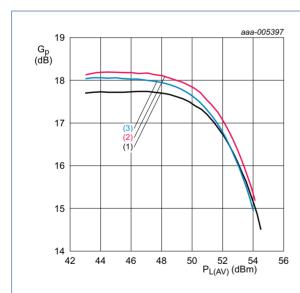


 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA.

- (1) f = 2112.5 MHz
- (2) f = 2140 MHz
- (3) f = 2167.5 MHz

Fig 14. Input return loss as a function of average output power; typical values

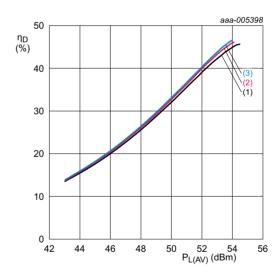
### 7.4.4 2-carrier W-CDMA



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA; 5 MHz carrier spacing.

- (1) f = 2115 MHz
- (2) f = 2140 MHz
- (3) f = 2165 MHz

Fig 15. Power gain as a function of average output power; typical values

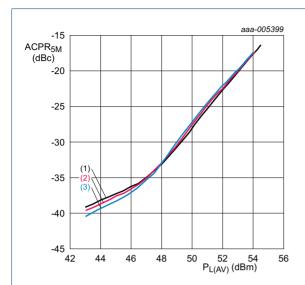


 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA; 5 MHz carrier spacing.

- (1) f = 2115 MHz
- (2) f = 2140 MHz
- (3) f = 2165 MHz

Fig 16. Drain efficiency as a function of average output power; typical values

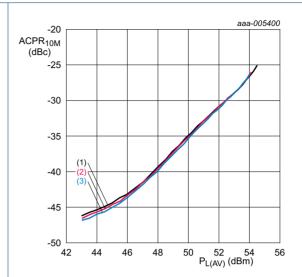
**Power LDMOS transistor** 



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA; 5 MHz carrier spacing.

- (1) f = 2115 MHz
- (2) f = 2140 MHz
- (3) f = 2165 MHz

Fig 17. Adjacent channel power ratio (5 MHz) as a function of average output power; typical values

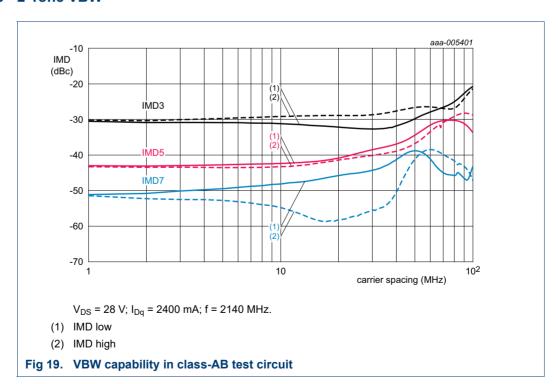


 $V_{DS}$  = 28 V;  $I_{Dq}$  = 2400 mA; 5 MHz carrier spacing.

- (1) f = 2115 MHz
- (2) f = 2140 MHz
- (3) f = 2165 MHz

Fig 18. Adjacent channel power ratio (10 MHz) as a function of average output power; typical values

### 7.4.5 2-Tone VBW



### 8. Package outline

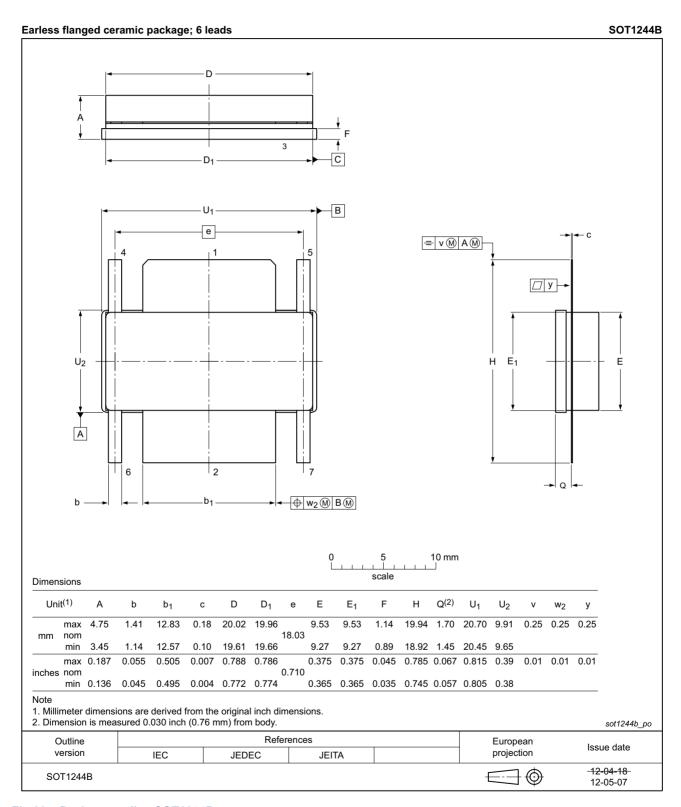


Fig 20. Package outline SOT1244B

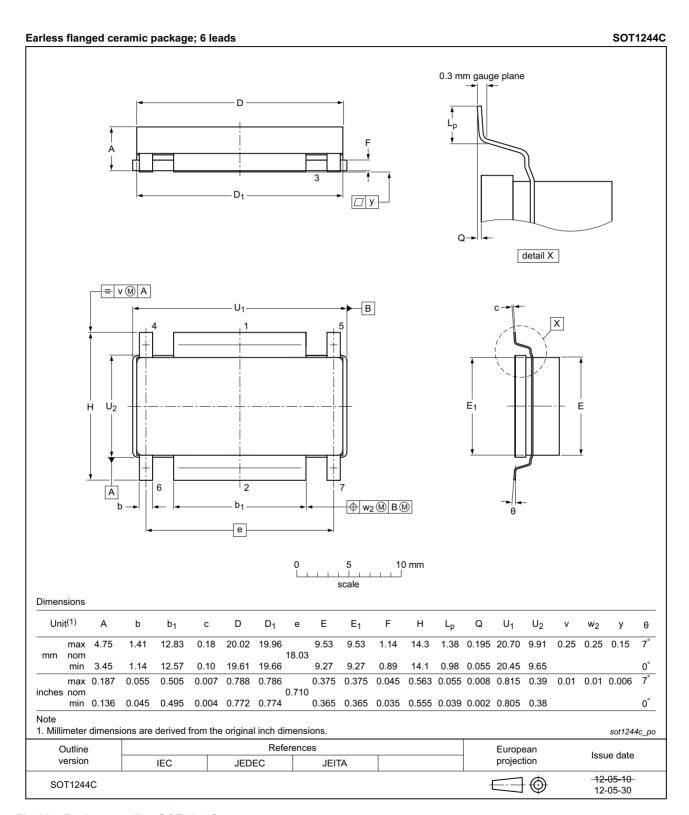


Fig 21. Package outline SOT1244C

# 9. Handling information

### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

# 10. Abbreviations

Table 10. Abbreviations

| Acronym | Description                                    |
|---------|--|
| 3GPP    | 3rd Generation Partnership Project             |
| CCDF    | Complementary Cumulative Distribution Function |
| CW      | Continuous Wave                                |
| DPCH    | Dedicated Physical Channel                     |
| ESD     | ElectroStatic Discharge                        |
| IS-95   | Interim Standard 95                            |
| LDMOS   | Laterally Diffused Metal Oxide Semiconductor   |
| PAR     | Peak-to-Average Ratio                          |
| SMD     | Surface Mounted Device                         |
| VBW     | Video BandWidth                                |
| VSWR    | Voltage Standing Wave Ratio                    |
| W-CDMA  | Wideband Code Division Multiple Access         |

# 11. Revision history

Table 11. Revision history

| Document ID                     | Release date   | Data sheet status    | Change notice | Supersedes                          |  |
|---------------------------------|--|----------------------|---------------|-------------------------------------|--|
| BLF8G22LS-270V_8G22LS-270GV#3   | 20150901   | Product data sheet   |               | BLF8G22LS-270V_8<br>G22LS-270GV v.2 |  |
| Modifications:                  | The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. |                      |               |                                     |  |
|                                 | <ul> <li>Legal texts have been adapted to the new company name where<br/>appropriate.</li> </ul>       |                      |               |                                     |  |
| BLF8G22LS-270V_8G22LS-270GV v.2 | 20121203   | Product data sheet   | -             | BLF8G22LS-270V_<br>8G22LS-270GV v.1 |  |
| BLF8G22LS-270V_8G22LS-270GV v.1 | 20120613   | Objective data sheet | -             | -                                   |  |

### 12. Legal information

### 12.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

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BLF8G22LS-270V 8G22LS-270GV#3

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**Power LDMOS transistor** 

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# **AMPLEON**

# **BLF8G22LS-270(G)V**

**Power LDMOS transistor** 

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